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## FCD380N60E N-Channel SuperFET<sup>®</sup> II Easy-Drive MOSFET 600 V, 10.2 A, 380 mΩ

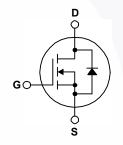
## Features

- 650 V @ T<sub>J</sub> = 150°C
- Typ. R<sub>DS(on)</sub> = 320 mΩ
- Ultra Low Gate Charge (Typ. Q<sub>g</sub> = 34 nC)
- Low Effective Output Capacitance (Typ. C<sub>oss(eff.)</sub> = 97 pF)
- 100% Avalanche Tested
- An Integrated Gate Resistor
- RoHS Compliant

## Description

SuperFET<sup>®</sup> II MOSFET is Fairchild Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Consequently, SuperFET II MOSFET easy-drive series offers slightly slower rise and fall times compared to the SuperFET II MOSFET series. Noted by the "E" part number suffix, this family helps manage EMI issues and allows for easier design implementation. For faster switching in applications where switching losses must be at an absolute minimum, please consider the Super-FET II MOSFET series.





### Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol	Parameter			FCD380N60E	Unit	
V <sub>DSS</sub>	Drain to Source Voltage			600	V	
V <sub>GSS</sub>	Cata ta Cauraa Maltaga	- DC		±20	V	
	Gate to Source Voltage	- AC	(f > 1 Hz)	±30	V	
ID	Drain Current	- Continuous (T <sub>C</sub> = 25 <sup>o</sup> C)		10.2		
	Drain Current	- Continuous (T <sub>C</sub> = 100 <sup>o</sup> C)		6.4	A	
I <sub>DM</sub>	Drain Current	- Pulsed	(Note 1)	30.6	А	
E <sub>AS</sub>	Single Pulsed Avalanche Energy (Note 2)		211.6	mJ		
I <sub>AR</sub>	Avalanche Current (Note 1)		2.3	Α		
E <sub>AR</sub>	Repetitive Avalanche Energy (Note 1)		1.06	mJ		
MOSFET dv/dt				100	Mag	
dv/dt	Peak Diode Recovery dv/dt (Note 3)			20	V/ns	
P <sub>D</sub>	Devues Dissignation	$(T_{\rm C} = 25^{\rm o}{\rm C})$		106	W	
	Power Dissipation	- Derate Above 25°C		0.85	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range			-55 to +150	°C	
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		Seconds	300	°C	

## Thermal Characteristics

Symbol	Parameter	FCD380N60E	Unit	
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	1.18	°C/W	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max.	100	°C/W	

December 2013

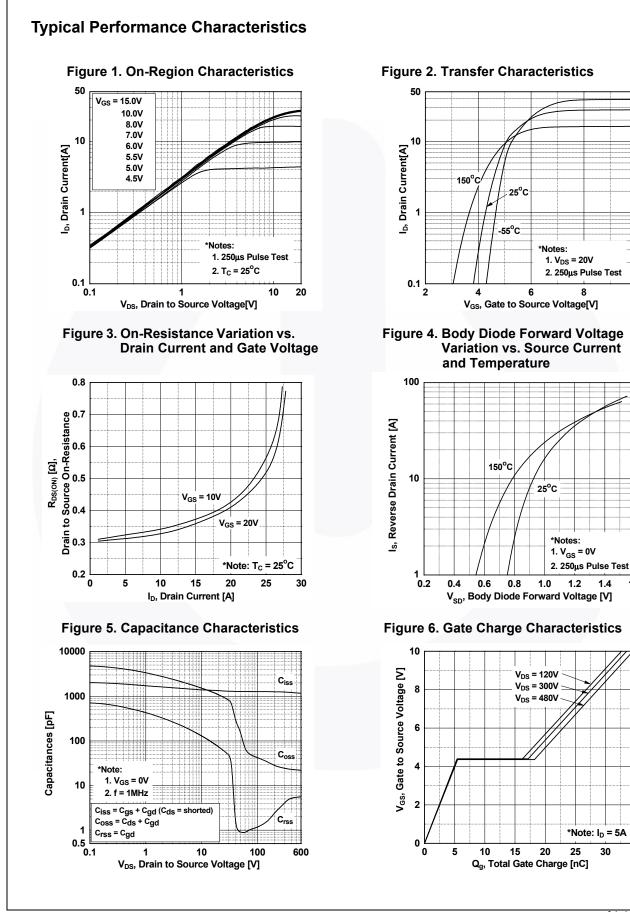
FCD380N60E — N-Channel SuperFET<sup>®</sup> II Easy-Drive MOSFET

	nber	Top Mark	Package	Packing Method	Reel Size	Тар	e Width	Qua	ntity
FCD380N	160E	FCD380N60E	DPAK	Tape and Reel	330 mm	1	6 mm	2500 units	
Electrica	l Chara	acteristics T <sub>C</sub> = 2	25°C unless c	therwise noted.					
Symbol		Parameter		Test Conditio	ons	Min.	Тур.	Max.	Unit
Off Charac	teristics	3							
			taga	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 10 mA, T <sub>J</sub> = 25°C		600	-	-	v
BV <sub>DSS</sub>			laye	$V_{GS}$ = 0 V, I <sub>D</sub> = 10 mA, T <sub>J</sub> = 150°C		650	-	-	v
ΔBV <sub>DSS</sub> / ΔT <sub>J</sub>	Breakdown Voltage Temperature Coefficient		e	I <sub>D</sub> = 10 mA, Referenced to 25°C		-	0.67	-	V/ºC
BV <sub>DS</sub>	Drain to Source Avalanche Breakdown Voltage		akdown	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 10 A		-	700	-	V
	Zero Gat	Zero Gate Voltage Drain Current		$V_{DS}$ = 480 V, $V_{GS}$ = 0 V		-	-	5	μA
DSS				V <sub>DS</sub> = 480 V, T <sub>C</sub> = 125°C		-	-	20	μΑ
GSS	Gate to I	Body Leakage Current		$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$		-	-	±100	nA
On Charac	teristics	5							
V <sub>GS(th)</sub>	Gate Th	reshold Voltage		V <sub>GS</sub> = V <sub>DS</sub> , I <sub>D</sub> = 250 μA		2.5	-	3.5	V
R <sub>DS(on)</sub>		rain to Source On Resis	stance	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 5 \text{ A}$		-	0.32	0.38	Ω
9FS	Forward Transconductance			$V_{DS} = 20 \text{ V}, \text{ I}_{D} = 5 \text{ A}$		-	10	-	S
Dynamic C	haracte	ristics							
C <sub>iss</sub>	-	pacitance				-	1330	1770	pF
C <sub>oss</sub>	Output C	Capacitance		— V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz		-	945	1260	pF
C <sub>rss</sub>	Reverse	Transfer Capacitance				-	60	90	pF
C <sub>oss</sub>	Output Capacitance			V <sub>DS</sub> = 380 V, V <sub>GS</sub> = 0 V, f = 1 MHz		-	25	-	pF
C <sub>oss(eff.)</sub>	Effective	Effective Output Capacitance		$V_{DS} = 0 V$ to 480 V, $V_{GS} = 0 V$		-	97	-	pF
Q <sub>g(tot)</sub>	Total Gat	te Charge at 10V		V <sub>DS</sub> = 380 V, I <sub>D</sub> = 5 A,		-	34	45	nC
Q <sub>gs</sub>	Gate to S	te to Source Gate Charge		V <sub>GS</sub> = 10 V		-	5.3	-	nC
Q <sub>gd</sub>	Gate to I	Gate to Drain "Miller" Charge		(Note 4)		-	13	-	nC
ESR	Equivalent Series Resistance			f = 1 MHz		-	6	-	Ω
Switching	Charact	eristics							
d(on)	Turn-On Delay Time					-	17	44	ns
tr	Turn-On Rise Time Turn-Off Delay Time Turn-Off Fall Time			$V_{DD}$ = 380 V, I <sub>D</sub> = 5 A, $V_{GS}$ = 10 V, R <sub>G</sub> = 4.7 Ω (Note 4)		-	9	28	ns
d(off)						-	64	138	ns
t <sub>f</sub>						-	10	30	ns
Drain-Sou	rce Diod	e Characteristics					1		
I <sub>S</sub>	-	n Continuous Drain to S		Forward Current		-	-	10.2	А
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode F					-	-	30.6	A
V <sub>SD</sub>	Drain to Source Diode Forward Voltage		Voltage	$V_{GS} = 0V, I_{SD} = 5 A$		-	-	1.2	V
	Reverse	Recovery Time		$V_{GS} = 0V, I_{SD} = 5 A,$ $dI_F/dt = 100 A/\mu s$		-	240	-	ns
·rr	Reverse	Recovery Charge				-	3	-	μC

10

1.4

1.6

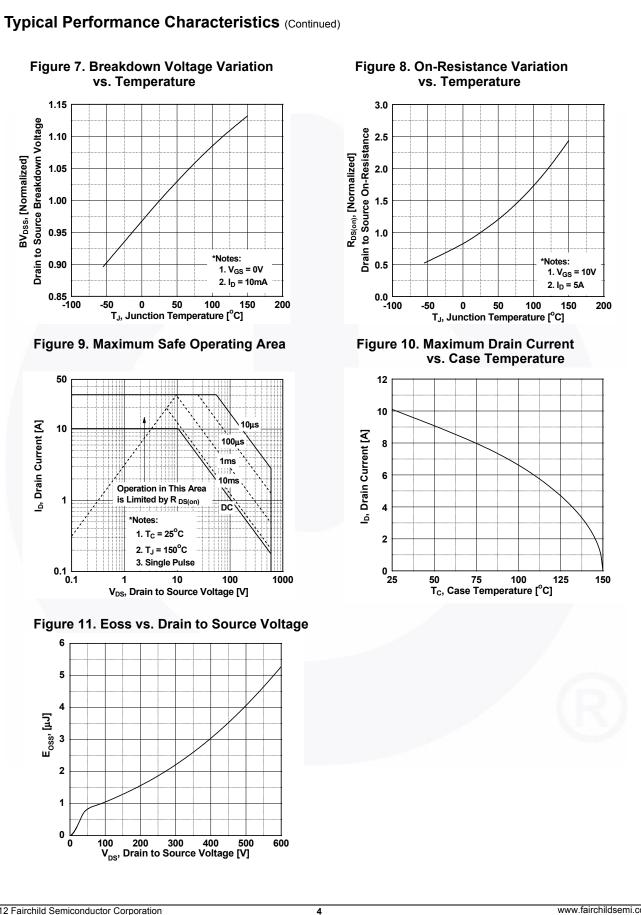


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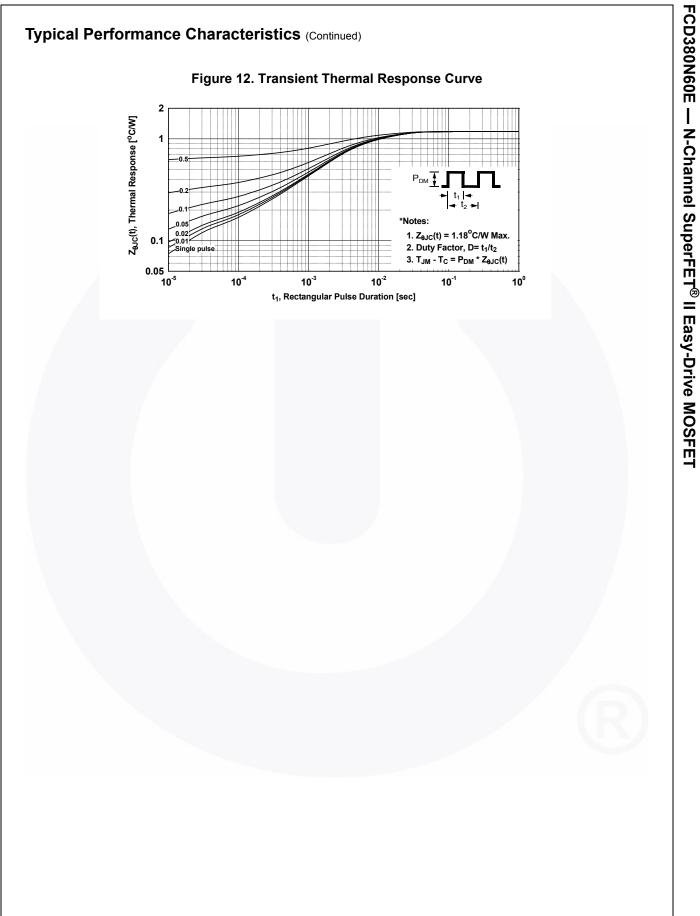
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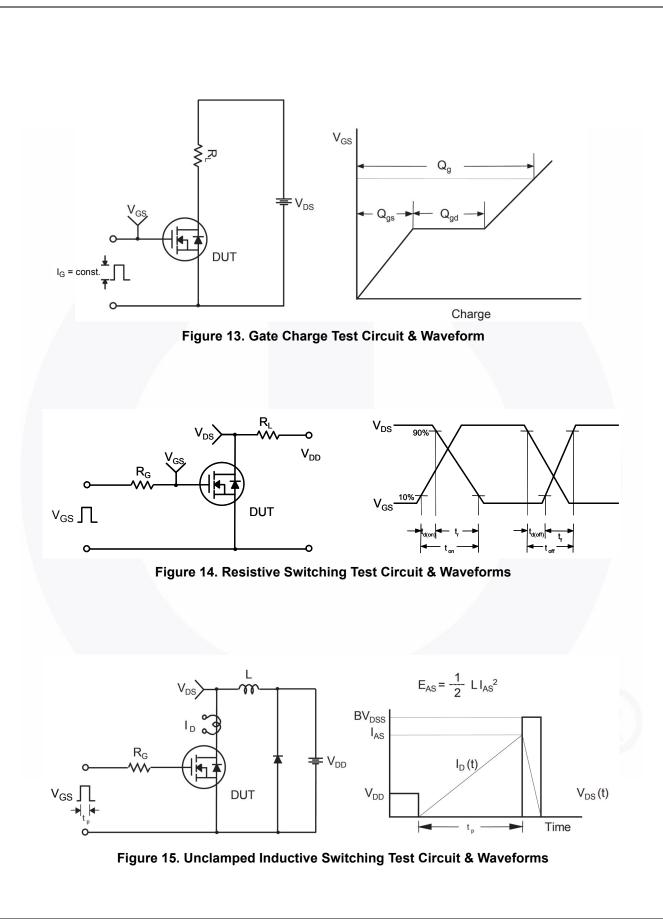
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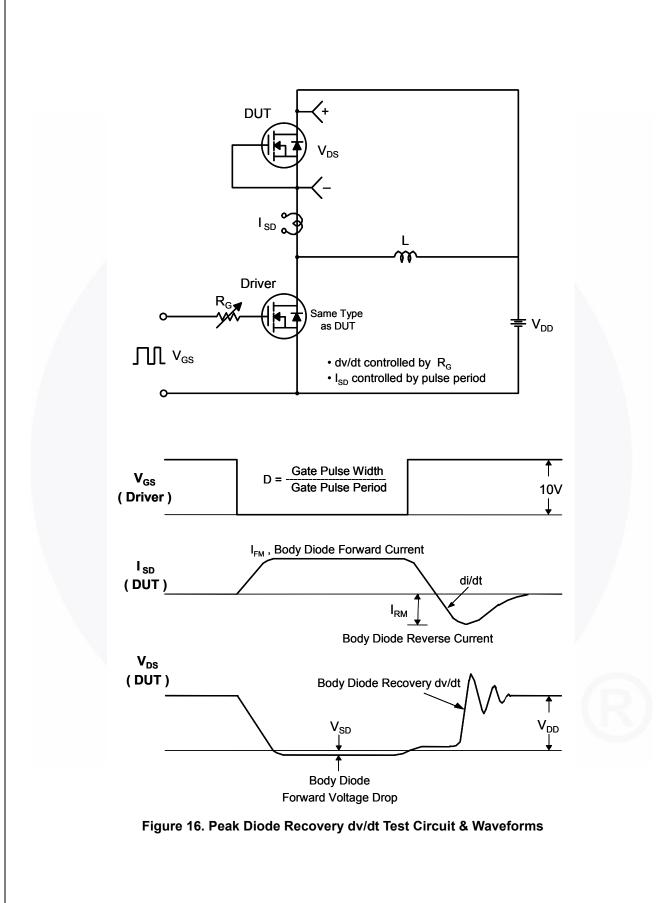


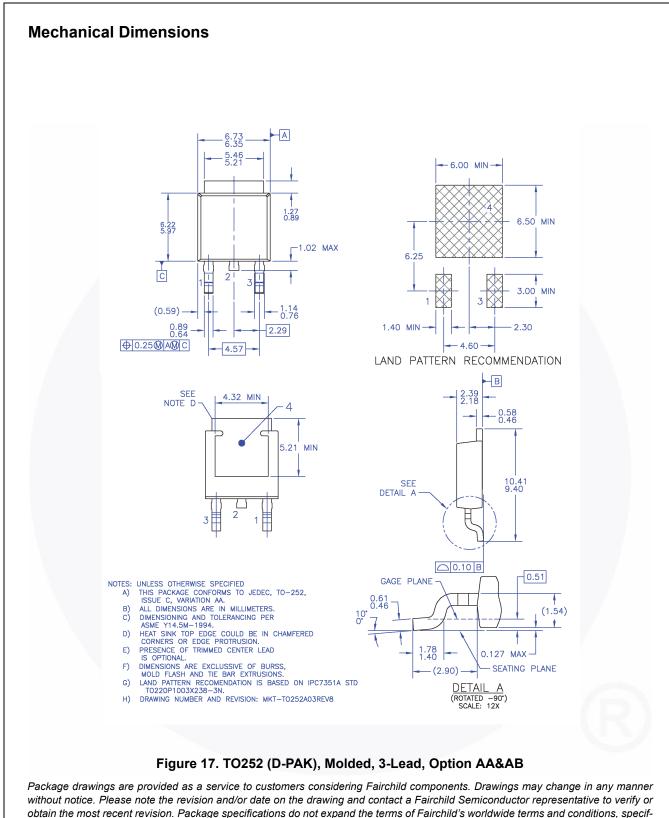
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